

L Numb r	Hits	Search T xt	DB	Time stamp
1	4	"6504585"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/10 08:57
2	1	"6504585" and video	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/10 08:57
3	4	"6249325"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/10 08:57
4	3	"6249325" and video	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/10 08:57
-	25	((substrate near5 transparent) and (gate and drain) and (tft or (thin near film near transistor)) and pixel and electrode and source and counter).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/04 16:23
-	20	((((substrate near5 transparent) and (gate and drain) and (tft or (thin near film near transistor)) and pixel and electrode and source and counter).clm.) and (source near electrode).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:43
-	42	((pixel near electrode) and (counter near electrode) and (source near electrode) and substrate and transparent).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:48
-	31	((((pixel near electrode) and (counter near electrode) and (source near electrode) and substrate and transparent).clm.) and (tft or (thin near film near transistor)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:51
-	29	(((((pixel near electrode) and (counter near electrode) and (source near electrode) and substrate and transparent).clm.) and (tft or (thin near film near transistor)).clm.) and (gate and drain).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:52
-	1	((((((pixel near electrode) and (counter near l ctr de) and (s urce near electrode) and substrate and transpar nt).clm.) and (tft r (thin n ar film near transist r)).clm.) and (gat and drain).clm.) and (matrix or array).clm.) and c nt ur.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:53

-	15	((((pixel near I trode) and (c unt r near electr de) and (s urce near el ctr de) and substrate and transparent).clm.) and (tft or (thin n ar film n ar transistor)).clm.) and (gat and drain).clm.) and (matrix or array).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:54
-	1	((((((pixel near electrode) and (counter near electrode) and (source near electrode) and substrate and transparent).clm.) and (tft or (thin near film near transistor)).clm.) and (gate and drain).clm.) and (matrix or array).clm.) and contour	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:55
-	2	((substrate near10 transparent) and (lcd or (liquid near crystal)) and (gate near line) and (drain near line) and (tft or (thin near film near transistor)) and (pixel near electrode) and (counter near electrode) and edge).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 10:58
-	7	((substrate near10 transparent) and (lcd or (liquid near crystal)) and (gate near line) and (drain near line) and (tft or (thin near film near transistor)) and (pixel near electrode) and (counter near electrode)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:02
-	146	((substrate near10 transparent) and (lcd or (liquid near crystal)) and (gate near line) and (drain near line) and (tft or (thin near film near transistor)) and (pixel near electrode) and (counter near electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:04
-	3	(((substrate near10 transparent) and (lcd or (liquid near crystal)) and (gate near line) and (drain near line) and (tft or (thin near film near transistor)) and (pixel near electrode) and (counter near electrode))) and (photoconductive or (photo near conductive))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:08
-	6	(((substrate near10 transparent) and (lcd or (liquid near crystal)) and (gate near line) and (drain near line) and (tft or (thin near film near transistor)) and (pixel near electrode) and (counter near electrode))) and (photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:09
-	13	fazli and erdem	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:09

-	6	(((substrat n ar10 transpar nt) and (lcd or (liquid near crystal)) and (gat near line) and (drain near lin) and (tft or (thin n ar film n ar transistor)) and (pixel n ar el ctr d) and (c unter near el ctr de))) and (photoconductiv r (ph to n ar c nductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:10
-	44	(US-6218206-\$ or US-6034747-\$ or US-5989945-\$ or US-5926161-\$ or US-5831707-\$ or US-5828430-\$ or US-5646756-\$ or US-5434433-\$ or US-5426313-\$ or US-5185601-\$ or US-5151806-\$ or US-4759610-\$ or US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did.	USPAT; US-PGPUB	2003/02/05 11:10

-	5	((US-6218206-\$ r US-6034747-\$ r US-5989945-\$ or US-5926161-\$ or US-5831707-\$ r US-5828430-\$ or US-5646756-\$ or US-5434433-\$ or US-5426313-\$ or US-5185601-\$ or US-5151806-\$ or US-4759610-\$ r US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did.) and (photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:12
-	39012	(photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:14
-	33053	((photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ti,ab,clm.) and (photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:14

-	1	(((ph t c nductiv or (photo near conductive) r ph toconduction or photoc nductivity r (photo near c nduct) or (phot n ar c ndu tivity) r (photo n ar condu ti n) or ph t c n).ti,ab,clm.) and (phot c nductiv or (phot n ar conductiv) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ab.) and (source and drain and gate and counter and pixel and (tft or (thin near film near transistor))).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:16
-	8	(((photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ti,ab,clm.) and (photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ab.) and (source and drain and gate and counter and pixel and (tft or (thin near film near transistor)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:17
-	13	((photoconductive or (photo near conductive) or photoconduction or photoconductivity or (photo near conduct) or (photo near conductivity) or (photo near conduction) or photocon).ti,ab,clm.) and (source and drain and gate and counter and pixel and (tft or (thin near film near transistor)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:17

-	56	(US-6218206-\$ or US-6034747-\$ r US-5989945-\$ or US-5926161-\$ r US-5831707-\$ or US-5828430-\$ r US-5646756-\$ r US-5434433-\$ r US-5426313-\$ r US-5185601-\$ or US-5151806-\$ r US-4759610-\$ or US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.	USPAT; US-PGPUB; DERWENT	2003/02/05 11:18
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	46	((US-6218206-\$ r US-6034747-\$ or US-5989945-\$ r US-5926161-\$ r US-5831707-\$ r US-5828430-\$ r US-5646756-\$ r US-5434433-\$ r US-5426313-\$ r US-5185601-\$ r US-5151806-\$ r US-4759610-\$ or US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:19
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	22	<p>(((US-6218206-\$ or US-6034747-\$ or US-5989945-\$ or US-5926161-\$ r US-5831707-\$ or US-5828430-\$ r US-5646756-\$ or US-5434433-\$ r US-5426313-\$ r US-5185601-\$ r US-5151806-\$ r US-4759610-\$ r US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)) and (gate near line) and (drain near line)</p>	<p>USPAT; US-PGPUB; EPO; JP ; DERWENT; IBM_TDB</p>	<p>2003/02/05 11:20</p>
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	17	<p>(((US-6218206-\$ r US-6034747-\$ or US-5989945-\$ or US-5926161-\$ or US-5831707-\$ or US-5828430-\$ or US-5646756-\$ r US-5434433-\$ r US-5426313-\$ r US-5185601-\$ r US-5151806-\$ r US-4759610-\$ r US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)) and (((gate near line) and (drain near line)) same (tft or (thin near film near transistor)))</p>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:21
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-	17	<p> ((((US-6218206-\$ r US-6034747-\$ r US-5989945-\$ r US-5926161-\$ r US-5831707-\$ r US-5828430-\$ r US-5646756-\$ or US-5434433-\$ r US-5426313-\$ r US-5185601-\$ or US-5151806-\$ r US-4759610-\$ r US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)) and (((gate near line) and (drain near line)) same (tft or (thin near film near transistor)))) and ((pixel near electrode) same (tft or (thin near film near transistor))) </p>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/05 11:21
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	14	<p> (((US-6218206-\$ r US-6034747-\$ or US-5989945-\$ or US-5926161-\$ or US-5831707-\$ r US-5828430-\$ or US-5646756-\$ or US-5434433-\$ r US-5426313-\$ or US-5185601-\$ r US-5151806-\$ or US-4759610-\$ or US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)) and (((gate near line) and (drain near line)) same (tft or (thin near film near transistor)))) and ((pixel near electrode) same (counter near electrode)) </p>	USPAT; US-PGPUB; EPO; JP ; DERWENT; IBM_TDB	2003/02/05 11:22
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	13	<p> ((((US-6218206-\$ r US-6034747-\$ r US-5989945-\$ or US-5926161-\$ r US-5831707-\$ or US-5828430-\$ r US-5646756-\$ r US-5434433-\$ or US-5426313-\$ or US-5185601-\$ r US-5151806-\$ or US-4759610-\$ or US-6500702-\$ or US-6486934-\$ or US-6452658-\$ or US-6449026-\$ or US-6362032-\$ or US-6335148-\$ or US-6323051-\$ or US-6319760-\$ or US-6309903-\$ or US-6292241-\$ or US-6226060-\$ or US-6219118-\$ or US-6097452-\$ or US-6091467-\$).did. or (US-5990987-\$ or US-5953084-\$ or US-5818550-\$ or US-5734455-\$ or US-6323918-\$ or US-5929958-\$ or US-5914762-\$ or US-5798744-\$ or US-5751381-\$ or US-6344885-\$ or US-6255131-\$ or US-6340818-\$ or US-6340812-\$ or US-5589961-\$ or US-5455883-\$ or US-5151688-\$ or US-6342700-\$ or US-5962856-\$ or US-5949502-\$ or US-5258705-\$ or US-4938567-\$).did. or (US-20020100908-\$ or US-20010052951-\$ or US-20010030717-\$ or US-20010015440-\$ or US-20020113916-\$ or US-20020074547-\$ or US-20020033907-\$).did. or (JP-09222597-\$ or US-20010052951-\$).did.) and (substrate near10 transparent)) and (((gate near line) and (drain near line)) same (tft or (thin near film near transistor)))) and ((pixel near electrode) same (counter near electrode))) and ((source near electrode) same (tft or (thin near film near electrode))) </p>	USPAT; US-PGPUB; EPO; JP ; DERWENT; IBM_TDB	2003/02/05 11:24
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